amantys

Dual Channel On-module Gate Drive Datasheet

Note: There are no TVS diodes to clamp over-voltage during turn-off.

Standards (refer to table on next page for full details)

- EN 50155 compliant for railway applications (when conformally coated)
- Thermal shock and vibration to IEC 61373
- EMC compliant to EN 50121-3-2, EN 50121-5, IEC 61800-3

Absolute Maximum Ratings

Permanent damage may occur if the Absolute Maximum Ratings are exceeded.

Parameter	Notes	Units	Min	Тур	Max
Supply Voltage	15V input variant	V			16.5
	24V input variant	V			30.0

Power Supply Characteristics

All data refers to +25 °C unless otherwise stated

Parameter	Notes		Min	Тур	Max
Nominal Supply Voltage (VDC)	A current limited supply (<2.0A) is		14.5	15.0	15.5
	recommended	V	21.6	24.0	27.6
Supply current with 15V input	upply current with 15V input Without load, not switching, OFF			110	120
	Operation at 3kHz into an IGBT module			160	
	(equivalent to ~110nF capacitor)				

General Electrical Characteristics

All data refers to +25 °C unless otherwise stated

Notes	Units Min T		Тур	Max
Internal power supply of gate drive depends on	V		10.0	
IGBT or SIC MOSFET				
Primary to output	pF		5	8
50Hz AC for 10 seconds, primary to output	Vrms			7400
	V	14.5	15.0	22.0
	V	-10.5	-10.0	-4.0
Rg(on)	Ω		TBC	
Rg(off)	Ω		TBC	
Rg(soft-off)	Ω		TBC	
Cge	nF		TBC	
Limited by gate resistors	А			32.0
Continuous operation, current is limited to	W			12.0
prevent overload under abnormal conditions				
Primary to secondary side, AE17 is 1700V only	V			3300
Time from PWM to gate voltage check	μs		80	
Fault if gate voltage below this level at GMT	V	13.4	13.8	14.2
aturation Detect Time Time from PWM to desaturation check, type I SC			7	
Desaturation Filter Delay Delay from desaturation to turn-off, type II SC			4	
Desaturation Fault Lockout Time for which the IGBT is held off after fault ms			17	
	Internal power supply of gate drive depends on IGBT or SiC MOSFET Primary to output 50Hz AC for 10 seconds, primary to output Rg(on) Rg(off) Rg(soft-off) Cge Limited by gate resistors Continuous operation, current is limited to prevent overload under abnormal conditions Primary to secondary side, AE17 is 1700V only Time from PWM to gate voltage check Fault if gate voltage below this level at GMT Time from PWM to desaturation check, type I SC Delay from desaturation to turn-off, type II SC	Internal power supply of gate drive depends on V IGBT or SiC MOSFET pF Primary to output pF 50Hz AC for 10 seconds, primary to output Vrms V V Rg(on) Ω Rg(off) Ω Cge nF Limited by gate resistors A Continuous operation, current is limited to W Primary to secondary side, AE17 is 1700V only V Time from PWM to gate voltage check µs Fault if gate voltage below this level at GMT V Time from PWM to desaturation check, type I SC µs Delay from desaturation to turn-off, type II SC µs	Internal power supply of gate drive depends on V IGBT or SiC MOSFET pF Primary to output pF 50Hz AC for 10 seconds, primary to output Vrms 50Hz AC for 10 seconds, primary to output V 7 V 14.5 8 V 9 -10.5 8 Q 10 Ω 8 Q 10 Q 10 Q 10 Q 11 Q 12 Q 13 Q 14.5 Q 14.5 Q 14.5 Q 16 Q 17 Q 18 Q 10 Q 10 Q 11 Q 12 Q 13.4 Time from PWM to gate voltage check 12 P 13.4 Time from PWM to desaturation check, type I SC 12 P 13.4 Time from desaturation to turn-off,	Internal power supply of gate drive depends on IGBT or SiC MOSFETV10.0Primary to outputpF550Hz AC for 10 seconds, primary to outputVrmsV14.515.0V-10.5-10.0Rg(on)ΩTBCRg(off)ΩTBCRg(soft-off)ΩTBCCgenFTBCLimited by gate resistorsAContinuous operation, current is limited to prevent overload under abnormal conditionsWPrimary to secondary side, AE17 is 1700V onlyV13.4Time from PWM to gate voltage checkµs80Fault if gate voltage below this level at GMTV13.4Time from PWM to desaturation check, type I SCµs4

Notes

[1]: The gate resistors and gate-emitter capacitance can be changed by agreement with Amantys

[2]: These parameters could be changed by agreement with Amantys

This datasheet describes a 2-channel Gate Drive for nHPD² and LinPak modules in a compact form. The AE00 variant is suitable for use with 3300V and 1700V IGBT and SiC modules and is designed to fit within the footprint of the module to minimise the overall size of the converter. The AE17 variant is suitable for use only with 1700V IGBT and SiC modules and has reduced height and clearance between the top and bottom boards.

The gate drive is qualified to international standards.

Features

- Compatible with nHPD² and LinPak modules
- High current drive into gate: 32A source, 30A sink
- 24V (A9) and 15V (A8) input voltage
- Operating temperature range: -40°C to +85°C
- Type I and type II short circuit protection
- Power supply undervoltage protection
- LED status indication
- IGBT and gate drive temperature encoded onto the fibre-optic optput
- Lead free design, RoHS compliant
- 12 months warranty



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Physical Parameters

Parameter	Notes	Units	Min	Тур	Max
Length	All dimensions have a tolerance of +/- 0.5mm	mm			98
Width		mm			62
Height AE17		mm			37
Height AE00		mm			47
Weight		g		80	
Screw torque	Maximum torque on gate, emitter and collector	Nm			2.0

Standards Compliance

All data refers to +25°C unless otherwise stated

Test	Notes	Test Standard	
Impulse test	18 kV 1.2/50 µs primary to output	Type test	
Dielectric test	7.4 kVrms primary to output, 50 Hz, 60 sec	Type test	
Partial discharge	≥2.6 kV rms extinction, <10 pC, input to output	Type test and production test	
EMC Immunity		EN 50121-3-2 Rolling Stock	
		EN 50121-5 Trackside	
		IEC 61800-3 Variable Speed Drives	
Electrostatic discharge	Air ±8 kV, contact ±6 kV, Perf Criterion B	IEC 61000-4-2	
	ESD precations must be taken when handling the core.		
Radiated immunity	10 V/m 80-2000 MHz, Perf Criterion A	IEC 61000-4-3	
Fast burst immunity	±4 kV, Perf Criterion A	IEC 61000-4-4	
Surge immunity	±2 kV, Perf Criterion B	IEC 61000-4-5	
Conducted immunity	10 Vrms, Perf Criterion A	IEC 61000-4-6	
Magnetic field immunity	100 A/m AC, 300 A/m DC, Perf Criterion A	IEC 61000-4-8	
Damped osc. voltage	2.5 kV line-earth, Perf Criterion B	IEC 61000-4-12	
Radiated emissions (E-field)	20-230/230-1000 MHz, 50/57 dBµV/m q-pk, 3 m	EN 55011 class A, group 1	
Conducted emissions	0.15-0.5/0.5-30 MHz 99/93 dBµV/m quasi-pk	EN 55016-2-1	

General specifications

All data refers to +25°C unless otherwise stated

Parameter	Notes	Units	Min	Тур	Max
Operating temperature	0°		-40		85
Storage temperature	°C -40		-40		85
Humidity	Compliant to EN 50155 Railways Applications	%		85	95
	Electronic Equipment Used on Rolling Stock with	conformal	coating		
Material flammability rating	UL94V-0 rated				
Pollution degree	Class 2				
Maximum altitude	Derate above this: Amantys to advise	m			2000
Environmental compliance	Reach compliant				
	RoHS compliant				
Creepage	Protective separation (Mat. Grp. 2)	mm	31.3		
	Functional isolation (Mat. Grp. 2)	mm	15.6		
Clearance	Protective separation (Mat. Grp. 2)	mm	19.3		
	Functional isolation (Mat. Grp 2)	mm	10.5		

[5] AE17 has reduced clearance between the top and bottom boards

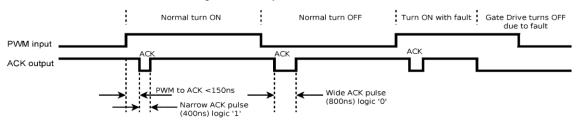
Power Supply Interface

Manufacturer	Required Plug Part Number	Pin Number	
Phoenix Contact	1925692 (FKC 2,5/ 2-ST-5,08-RF)	1	2
Amantys part number	EC001150	VDC	GND

Fibre-optic Interface (see picture to identify upper and lower interfaces)

Interface	Description	Manufacturer	Part Number	Encoding
Optical input (PWM)	Receiver (Black)	Firecomms	FR50MWIR	Light ON = IGBT ON
Optical output (ACK)	Transmitter (Grey)	Firecomms	FT10MWLR	Light ON = OK, OFF = Fault

The feedback protocol on the optical output (ACK) is the Amantys compatibility mode. One ACK pulse for each PWM edge. The gate drive and NTC temperature measurements are encoded into a Power Insight data packet (NALP frame). The temperature measurements can be decoded by the Power Insight Adapter or FPGA design licensed from Amantys. The gate drive must be receiving incoming PWM pulses and sends the data by modulating the ACK pulse width. At power up the application software part number is sent, followed by the temperature data continuously. This information is transmitted from the lower gate drive only.

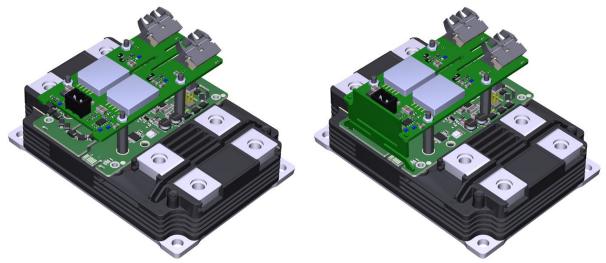


Time is measured at the gate drive and does not include propagation delay or pulse distortion of fibre-optic transceivers



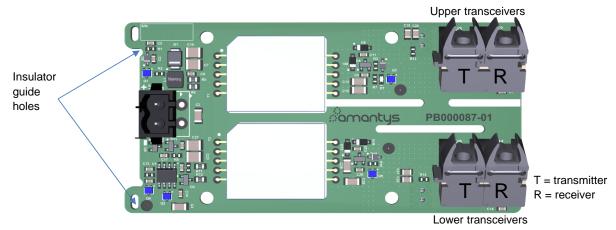
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Mechanical Drawing Please ask Amantys for 3D model (PDF or STEP file) when planning converter layout.

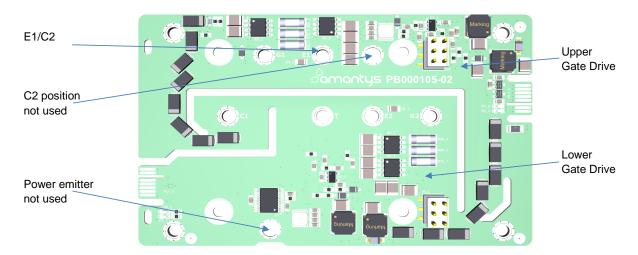


Gate Drive Assembly on IGBT Module (a) without insulator, (b) with insulator

Note: If IGBTs are mounted closer than 9mm apart then an insulator PCB can be used between gate drives to maintain clearance distance between adjacent modules.



Top view of top board showing fibre-optic transceivers and power input connector



Top View of bottom board showing IGBT connections

Note: To avoid shorting copper tracks on the PCB, the screw header including any washer must not exceed the available metallic terminal pad of the bottom board. The maximum diameter is 5.6mm.

PRELIMINARY



LED Status Indication

Each channel of the gate drive has two LEDs that communicate the status of the gate drive

LED	Behaviour	Status
Green	Lit continuously	Supply OK
Red	Lit continuously	Power supply below minimum voltage (under-voltage) or fault

When the fault is removed the red LED will stay on until the board is power cycled.

Ordering Information

Part Number	AE00NB8SX-YYYYY	3300V or 1700V with vertical power connector 15V input
	AE00NB9SX-YYYYY	3300V or 1700V with vertical power connector 24V input
	AE17NB8SX-YYYYY	1700V with vertical power connector 15V
	AE17NB9SX-YYYYY	1700V with vertical power connector 24V
	where V O (where the d) ar	

where X = 0 (uncoated) or C (coated)

 $N = nHPD^2/LinPak$

YYYYY = specific part number for each configuration of resistors and PLD, e.g. 00137

Notes

A horizontal power connector may be an option, however modules must be spaced to avoid interference between the power connector and fibre-optic tranceivers on the adjacent module. The insulator PCB cannot be used.

Broadcomm fibre-optic transceivers may be used if Firecomms parts are not available.

Legal Disclaimer

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Important Information



The data contained herein is intended exclusively for qualified engineers who are experienced with, and trained in, working with high voltage apparatus which involves risk to life. Strict compliance with all relevant safety regulations for the target application is essential. Any handling of electronic devices is subject to the general specifications for protecting electrostatic sensitive devices according to international standard IEC 747-1, Chapter IX or European standard EN 100015 (i.e. the workplace, tool, operating environment, etc. must comply with these standards). Failure to comply may lead to the product becoming damaged.